2SK3043

Silicon N-channel power MOSFET

■ Features

• Avalanche energy capability guaranteed: EAS > 100 mJ

 \bullet Gate-source surrender voltage V_{GSS} : $\pm 30~V$ guaranteed

• High-speed switching

• No secondary breakdown

■ Applications

- Non-contact relay
- · Solenoid drive
- Motor drive
- Control equipment
- Switching mode regulator

■ Absolute Maximum Ratings $T_C = 25$ °C

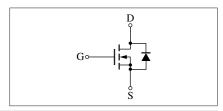
| Parameter | Symbol | Rating | Unit | |
|--------------------------------|------------------|-------------|------|--|
| Drain-source surrender voltage | V _{DSS} | 450 | V | |
| Gate-source surrender voltage | V _{GSS} | ±30 | V | |
| Drain current | I_{D} | ±5 | A | |
| Peak drain current | I_{DP} | ±10 | A | |
| Avalanche energy capability * | EAS | 100 | mJ | |
| Power dissipation | P _D | 35 | W | |
| $T_a = 25^{\circ}C$ | | 2 | | |
| Channel temperature | T _{ch} | 150 | °C | |
| Storage temperature | T _{stg} | -55 to +150 | °C | |

Note) *: L = 8 mH, $I_L = 5$ A, 1 pulse

Unit: mm 4.6±0.2 9.9±0.3 2.9±0.2 φ 3.2±0.1 15.0±0.5 1.4±0.2 2.6±0.1 1.6+0.2 13.7±0.2 0.55±0.15 5.08±0.50 1: Gate 2: Drain 3: Source TO-220D-A1 Package

Marking Symbol: K3043

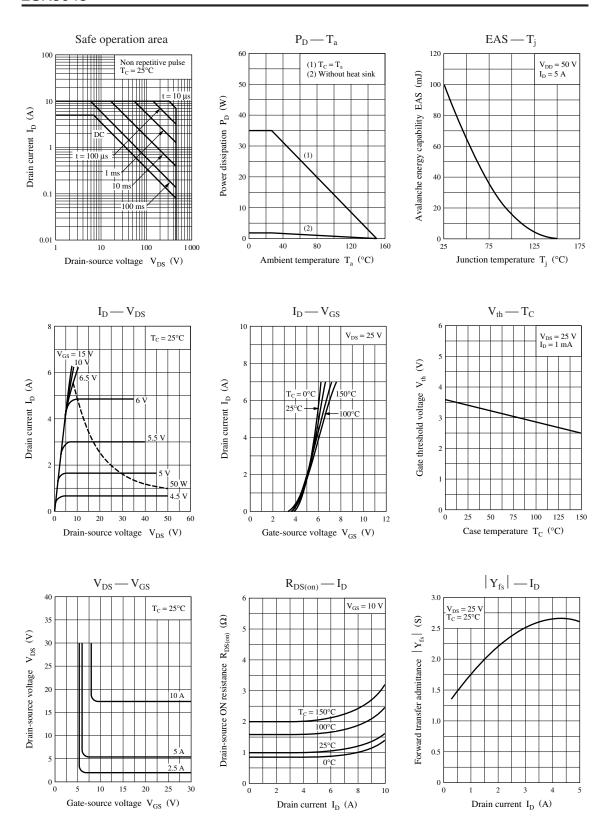
Internal Connection



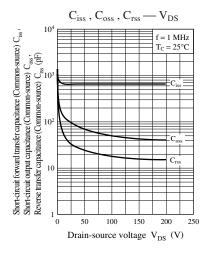
■ Electrical Characteristics $T_C = 25$ °C ± 3 °C

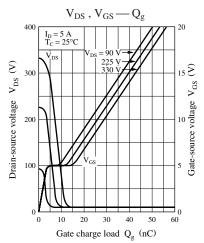
| Parameter | Symbol | Conditions | Min | Тур | Max | Unit |
|--|-----------------------|--|-----|-----|------|------|
| Drain-source surrender voltage | V _{DSS} | $I_D = 1 \text{ mA}, V_{GS} = 0$ | 450 | | | V |
| Drain-source cutoff current | I_{DSS} | $V_{DS} = 360 \text{ V}, V_{GS} = 0$ | | | 100 | μΑ |
| Gate-source cutoff current | I_{GSS} | $V_{GS} = \pm 30 \text{ V}, V_{DS} = 0$ | | | ±1 | μΑ |
| Gate threshold voltage | V _{th} | $V_{DS} = 25 \text{ V}, I_{D} = 1 \text{ mA}$ | 2.0 | | 5.0 | V |
| Forward transfer admittance | Yfs | $V_{DS} = 25 \text{ V}, I_{D} = 3 \text{ A}$ | 1.8 | 2.5 | | S |
| Drain-source ON resistance | R _{DS(on)} | $V_{GS} = 10 \text{ V}, I_D = 3 \text{ A}$ | | 1.0 | 1.3 | Ω |
| Diode forward voltage | V_{DF} | $I_{DR} = 5 \text{ A}, V_{GS} = 0$ | | | -1.2 | V |
| Short-circuit forward transfer capacitance (Common source) | C _{iss} | $V_{DS} = 20 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$ | | 700 | | pF |
| Short-circuit output capacitance (Common source) | C _{oss} | | | 100 | | pF |
| Reverse transfer capacitance (Common source) | C _{rss} | | | 40 | | pF |
| Turn-on delay time | t _{d(on)} | $V_{DD} = 150 \text{ V}, I_D = 3 \text{ A}, R_L = 50 \Omega$ | | 25 | | ns |
| Rise time | t _r | $V_{GS} = 10 \text{ V}$ | | 45 | | ns |
| Fall time | $t_{\rm f}$ | | | 35 | | ns |
| Turn-off delay time | t _{d(off)} | | | 80 | | ns |
| Thermal resistance (ch-c) | R _{th(ch-c)} | | | | 3.5 | °C/W |
| Thermal resistance (ch-a) | R _{th(ch-a)} | | | | 62.5 | °C/W |

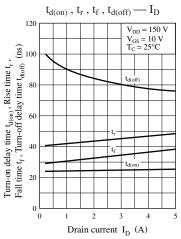
Note) Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

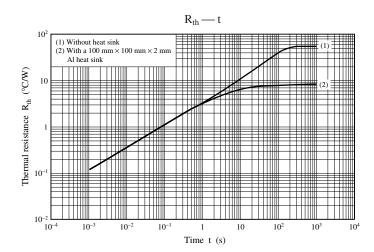


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